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Growth and Phase Transformations of Ir on Ge(111)

C.H. Mullet, B.H. Stenger, A.M. Durand, J.A. Morad, Y. Sato, E.C. Poppenheimer, S. Chiang

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Highlights

- Ir deposited on Ge(111) at 350° C shows island growth with interconnecting bridges.
- For deposition onto substrates above 500° C, Ir forms dendritic growth patterns.
- Ir on Ge(111) forms a (√3 x √3)R30° overlayer in LEEM images at 2.0 ML coverage.
- Compact Ir islands form at higher coverage.

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